



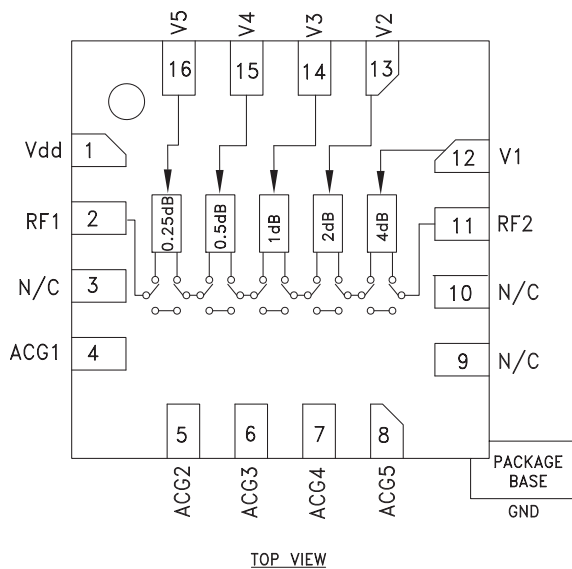
0.25 dB LSB GaAs MMIC 5-BIT DIGITAL POSITIVE CONTROL ATTENUATOR, DC - 4 GHz

Typical Applications

The HMC539LP3 / HMC539LP3E is ideal for both RF and IF applications:

- Cellular Infrastructure
- ISM, MMDS, WLAN, WiMAX, WiBro
- Microwave Radio & VSAT
- Test Equipment and Sensors

Functional Diagram



Features

- 0.25 dB LSB Steps to 7.75 dB
- ± 0.05 dB Typical Step Error
- Low Insertion Loss: 0.7 dB
- High IP3: +50 dBm
- Single Control Line Per Bit
- TTL/CMOS Compatible Control
- Single +5V Supply
- 3x3 mm SMT Package

General Description

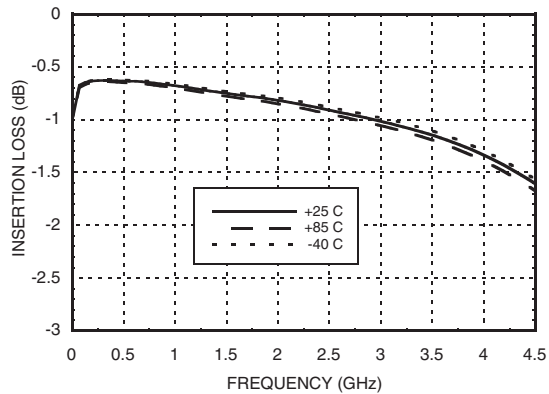
The HMC539LP3 & HMC539LP3E are broadband 5-bit GaAs IC digital attenuators in low cost lead-less surface mount packages. This single positive control line per bit digital attenuator utilizes an off chip AC ground capacitor for near DC operation, making it suitable for a wide variety of RF and IF applications. Covering DC to 4 GHz, the insertion loss is less than 0.7 dB typical. The attenuator bit values are 0.25 (LSB), 0.5, 1, 2, and 4 dB for a total attenuation of 7.75 dB. Attenuation accuracy is excellent at ± 0.05 dB typical step error. The attenuator also features a high IIP3 of +50 dBm. Five TTL/CMOS control inputs are used to select each attenuation state. A single Vdd bias of +5V is required.

Electrical Specifications,

$T_a = +25^\circ \text{C}$, With $V_{dd} = +5\text{V}$ & $V_{ctl} = 0/+5\text{V}$ (Unless Otherwise Noted)

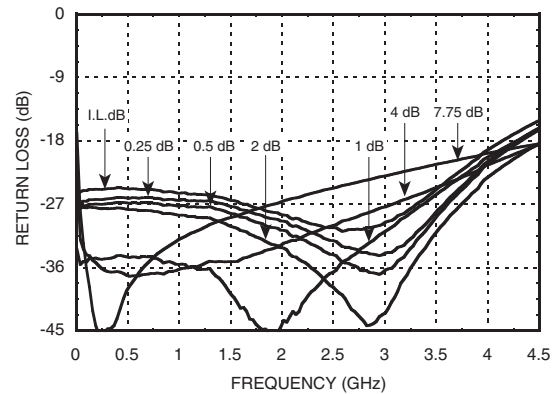
Parameter	Frequency (GHz)	Min.	Typ.	Max.	Units
Insertion Loss	DC - 1.5 GHz		0.7	1.0	dB
	1.5 - 3.0 GHz		1.0	1.3	dB
	3.0 - 4.0 GHz		1.3	1.7	dB
Attenuation Range	DC - 4 GHz		7.75		dB
Return Loss (RF1 & RF2, All Atten. States)	DC - 3 GHz		25		dB
	3.0 - 4.0 GHz		20		dB
Attenuation Accuracy: (Referenced to Insertion Loss)	All States DC - 3 GHz 3.0 - 4.0 GHz	± (0.2 + 2% of Atten. Setting) Max.			dB
		± (0.2 + 4% of Atten. Setting) Max.			dB
Input Power for 0.1 dB Compression	0.1 - 4.0 GHz		28		dBm
Input Third Order Intercept Point (Two-Tone Input Power = 0 dBm Each Tone)	0.1 - 4.0 GHz		50		dBm
Switching Characteristics	DC - 4 GHz				
		tRISE, tFALL (10/90% RF)		48	ns
		tON, tOFF (50% CTL to 10/90% RF)		52	ns

Insertion Loss



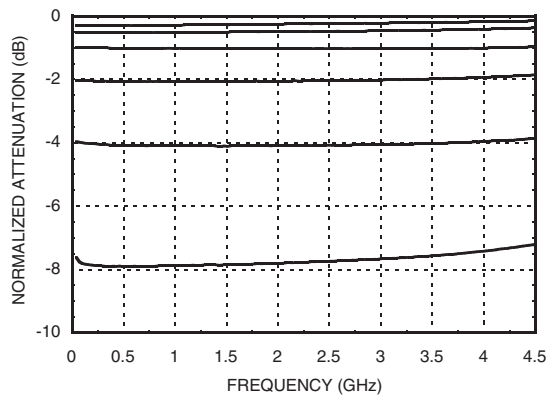
Return Loss RF1, RF2

(Only Major States are Shown)

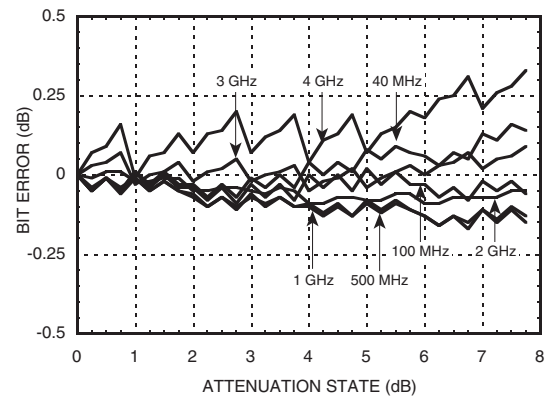


Normalized Attenuation

(Only Major States are Shown)

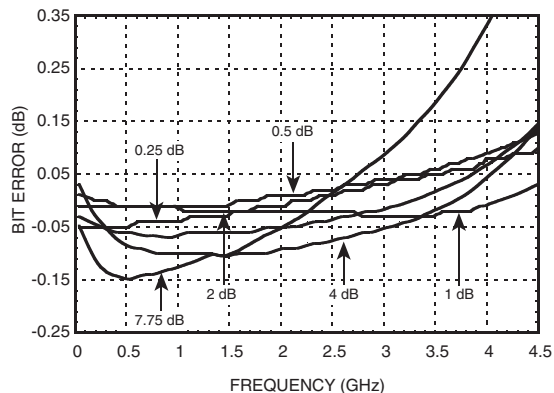


Bit Error vs. Attenuation State



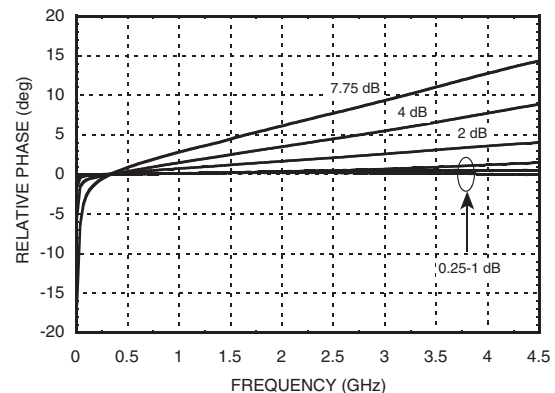
Bit Error vs. Frequency

(Only Major States are Shown)



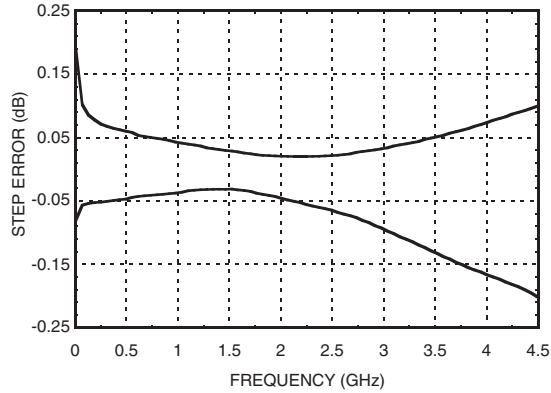
Relative Phase vs. Frequency

(Only Major States are Shown)





Worst Case Step Error Between Successive Attenuation States



Bias Voltage & Current

Vdd = +5.0 Vdc ± 10%	
Vdd (VDC)	Idd (Typ.) (mA)
+4.5	3.3
+5.0	3.5
+5.5	3.7

Control Voltage

State	Bias Condition
Low	0 to +0.8V @ -5 uA Typ.
High	+2.0 to + 5.0 Vdc @ 30 uA Typ.

Note: Vdd = +5V

Truth Table

Control Voltage Input					Attenuation State RF1 - RF2
V1 4 dB	V2 2 dB	V3 1 dB	V4 0.5 dB	V5 0.25 dB	
High	High	High	High	High	Reference I.L.
High	High	High	High	Low	0.25 dB
High	High	High	Low	High	0.5 dB
High	High	Low	High	High	1 dB
High	Low	High	High	High	2 dB
Low	High	High	High	High	4 dB
Low	Low	Low	Low	Low	7.75 dB

Any combination of the above states will provide an attenuation approximately equal to the sum of the bits selected.



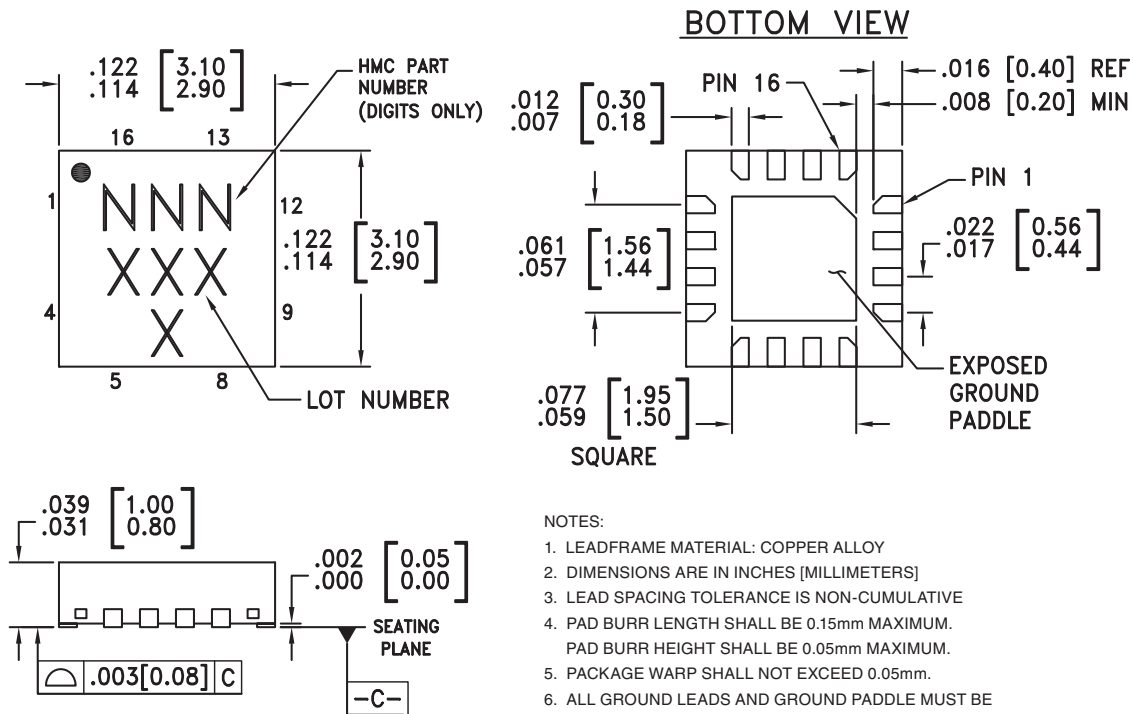
Absolute Maximum Ratings

RF Input Power (DC - 4 GHz)	+29 dBm (T = +85 °C)
Control Voltage Range (V1 to V5)	-1V to Vdd +1V
Bias Voltage (Vdd)	+7.0 Vdc
Channel Temperature	150 °C
Continuous P _{diss} (T = 85 °C) (derate 12.0 mW/°C above 85 °C)	0.781 W
Thermal Resistance	83 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 1A



ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS

Outline Drawing



Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[3]
HMC539LP3	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 ^[1]	539 XXXX
HMC539LP3E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 ^[2]	539 XXXX

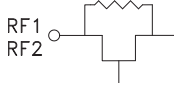
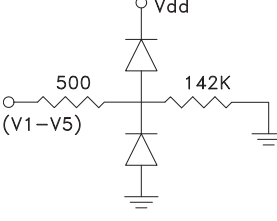

[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C

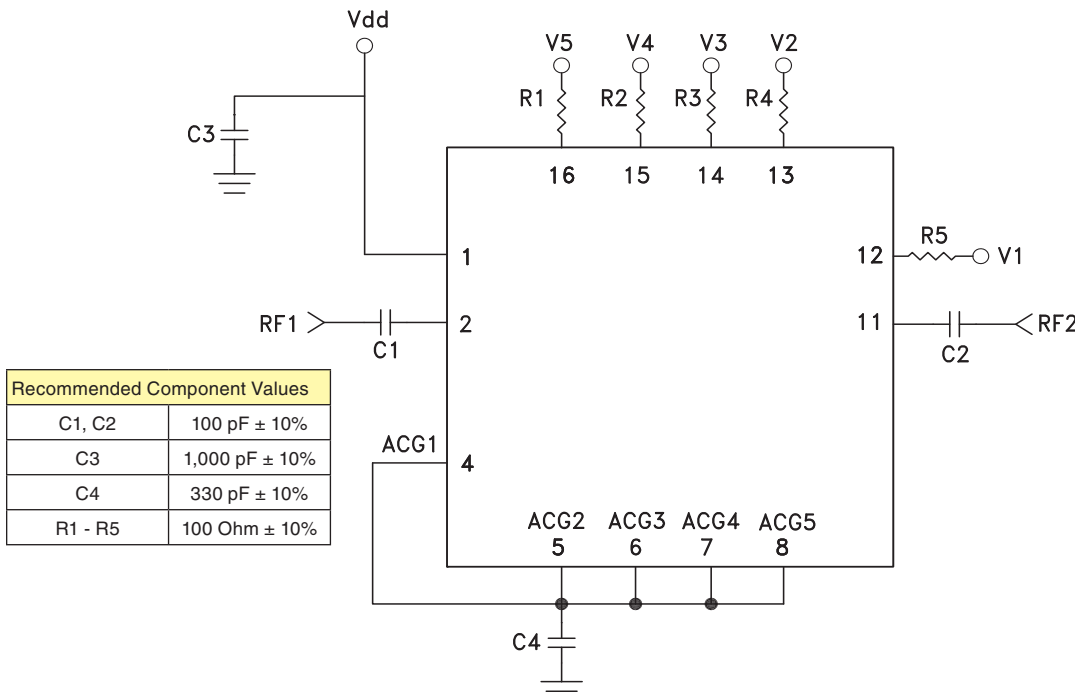
[3] 4-Digit lot number XXXX

For price, delivery, and to place orders, please contact Hittite Microwave Corporation:
20 Alpha Road, Chelmsford, MA 01824 Phone: 978-250-3343 Fax: 978-250-3373
Order On-line at www.hittite.com

Pin Descriptions

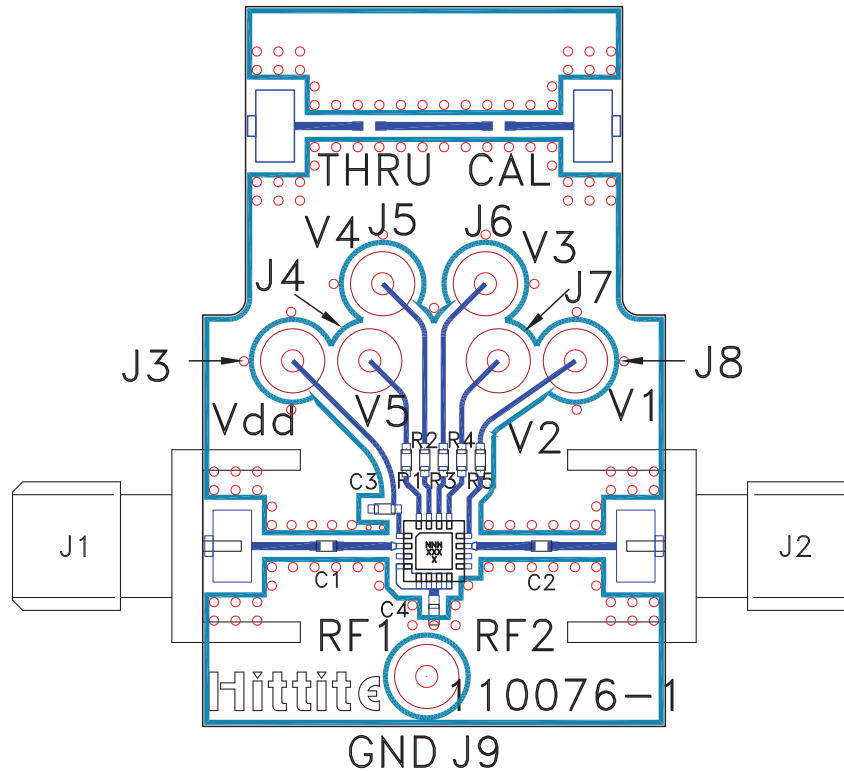
Pin Number	Function	Description	Interface Schematic
1	Vdd	Supply Voltage.	
2, 11	RF1, RF2	This pin is DC coupled and matched to 50 Ohm. Blocking capacitors are required. Select value based on lowest frequency of operation.	
3, 9, 10	N/C	These pins should be connected to PCB RF ground to maximize performance.	
4 - 8	ACG1 - ACG5	External capacitor to ground is required. Select value for lowest frequency of operation. Place capacitor as close to pins as possible.	
12 - 16	V1 - V5	See truth table and control voltage table.	
	GND	Package bottom has an exposed metal paddle that must be connected to RF Ground.	

Application Circuit





Evaluation PCB



List of Materials for Evaluation PCB 110078 [1]

Item	Description
J1 - J2	PCB Mount SMA Connector
J3 - J9	DC Pin
C1, C2	100 pF Capacitor, 0402 Pkg.
C3	1000 pF Capacitor, 0402 Pkg.
C4	330 pF Capacitor, 0402 Pkg.
R1 - R5	100 Ohm Resistor 0402
U1	HMC539LP3 / HMC539LP3E Digital Attenuator
PCB [2]	110076 Evaluation PCB

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.